



PHC2300

Complementary enhancement mode MOS transistors

Rev. 05 — 24 February 2011

Product data sheet

1. Product profile

1.1 General description

One N-channel and one P-channel enhancement mode Field-Effect Transistor (FET) in a plastic package. This product is designed and qualified for use in computing, communications, consumer and industrial applications only.

1.2 Features and benefits

- Suitable for high frequency applications due to fast switching characteristics

1.3 Applications

- High-speed line drivers
- Line transformer drivers
- Relay drivers
- Universal line interface in telephone sets

1.4 Quick reference data

Table 1. Quick reference data

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
|-------------------------------|----------------------------------|---|-----|-----|------|----------|
| V_{DS} | drain-source voltage | $T_j \geq 25\text{ °C}; T_j \leq 150\text{ °C};$ N-channel | - | - | 300 | V |
| | | $T_j \geq 25\text{ °C}; T_j \leq 150\text{ °C};$ P-channel | - | - | -300 | V |
| I_D | drain current | $T_{sp} = 80\text{ °C};$ N-channel | [1] | - | 340 | mA |
| | | $T_{sp} = 80\text{ °C};$ P-channel | [1] | - | -235 | mA |
| P_{tot} | total power dissipation | $T_{sp} = 80\text{ °C}$ | [2] | - | 1.6 | W |
| Static characteristics | | | | | | |
| $R_{DS(on)}$ | drain-source on-state resistance | $V_{GS} = 10\text{ V}; I_D = 170\text{ mA};$ $T_j = 25\text{ °C};$ N-channel | - | - | 6 | Ω |
| | | $V_{GS} = -10\text{ V}; I_D = -115\text{ mA};$ $T_j = 25\text{ °C};$ P-channel | - | - | 17 | Ω |

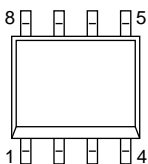
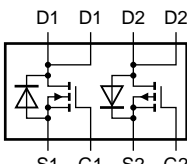
Table 1. Quick reference data ...continued

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
|--------------------------------|-------------------|---|-----|------|-----|------|
| Dynamic characteristics | | | | | | |
| Q_{GD} | gate-drain charge | $V_{GS} = -10\text{ V}$; $I_D = -115\text{ mA}$; $V_{DS} = -50\text{ V}$; $T_j = 25\text{ °C}$; P-channel | - | 674 | - | pC |
| | | $V_{GS} = 10\text{ V}$; $I_D = 170\text{ mA}$; $V_{DS} = 50\text{ V}$; $T_j = 25\text{ °C}$; N-channel | - | 1385 | - | pC |

- [1] Solder point temperature is the temperature at the soldering point of the drain leads.
- [2] Maximum permissible dissipation per MOS transistor (both devices may thus be loaded up to 1.6 W at the same time).

2. Pinning information

Table 2. Pinning information

| Pin | Symbol | Description | Simplified outline | Graphic symbol |
|-----|--------|-------------|--|---|
| 1 | S1 | source1 |  <p>SOT96-1 (SO8)</p> |  <p><i>sym114</i></p> |
| 2 | G1 | gate1 | | |
| 3 | S2 | source2 | | |
| 4 | G2 | gate2 | | |
| 5 | D2 | drain2 | | |
| 6 | D2 | drain2 | | |
| 7 | D1 | drain1 | | |
| 8 | D1 | drain1 | | |

3. Ordering information

Table 3. Ordering information

| Type number | Package | | |
|-------------|---------|---|---------|
| | Name | Description | Version |
| PHC2300 | SO8 | plastic small outline package; 8 leads; body width 3.9 mm | SOT96-1 |

4. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

| Symbol | Parameter | Conditions | Min | Max | Unit |
|-----------|-------------------------|---|-----|------|---------|
| V_{DS} | drain-source voltage | $T_j \geq 25\text{ °C}; T_j \leq 150\text{ °C}; \text{N-channel}$ | - | 300 | V |
| | | $T_j \geq 25\text{ °C}; T_j \leq 150\text{ °C}; \text{P-channel}$ | - | -300 | V |
| V_{GS} | gate-source voltage | | -20 | 20 | V |
| I_D | drain current | $T_{sp} = 80\text{ °C}; \text{N-channel}$ | [1] | - | 340 mA |
| | | $T_{sp} = 80\text{ °C}; \text{P-channel}$ | [1] | - | -235 mA |
| I_{DM} | peak drain current | $T_{sp} = 25\text{ °C}; \text{pulsed}; \text{N-channel}$ | [2] | - | 1.4 A |
| | | $T_{sp} = 25\text{ °C}; \text{pulsed}; \text{P-channel}$ | [2] | - | -0.9 A |
| P_{tot} | total power dissipation | $T_{sp} = 80\text{ °C}$ | [3] | - | 1.6 W |
| | | $T_{amb} = 25\text{ °C}$ | [4] | - | 1.8 W |
| | | $T_{amb} = 25\text{ °C}$ | [5] | - | 0.9 W |
| | | $T_{amb} = 25\text{ °C}$ | [6] | - | 1.2 W |
| T_{stg} | storage temperature | | -55 | 150 | °C |
| T_j | junction temperature | | -55 | 150 | °C |

- [1] Solder point temperature is the temperature at the soldering point of the drain leads.
- [2] Pulse width and duty cycle limited by maximum junction temperature.
- [3] Maximum permissible dissipation per MOS transistor (both devices may thus be loaded up to 1.6 W at the same time).
- [4] Maximum permissible dissipation per MOS transistor. Value based on a printed-circuit board with an $R_{th(a-tp)}$ (ambient to tie-point) of 27.5 K/W.
- [5] Maximum permissible dissipation per MOS transistor. Value based on a printed-circuit board with an $R_{th(a-tp)}$ (ambient to tie-point) of 90 K/W.
- [6] Maximum permissible dissipation if only one MOS transistor dissipates. Value based on a printed-circuit board with an $R_{th(a-tp)}$ (ambient to tie-point) of 90 K/W.

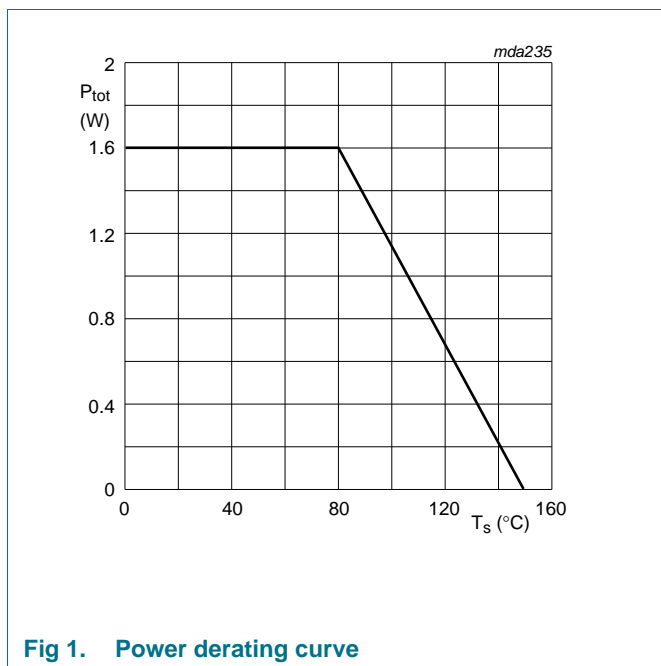


Fig 1. Power derating curve

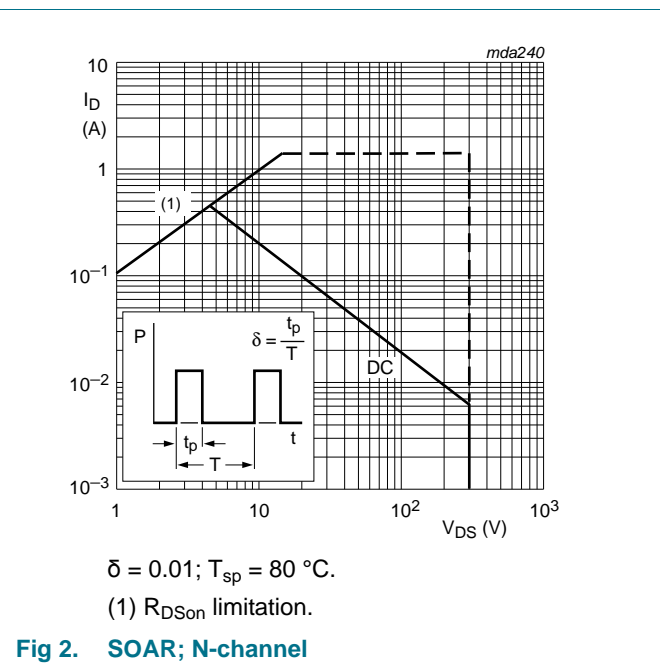
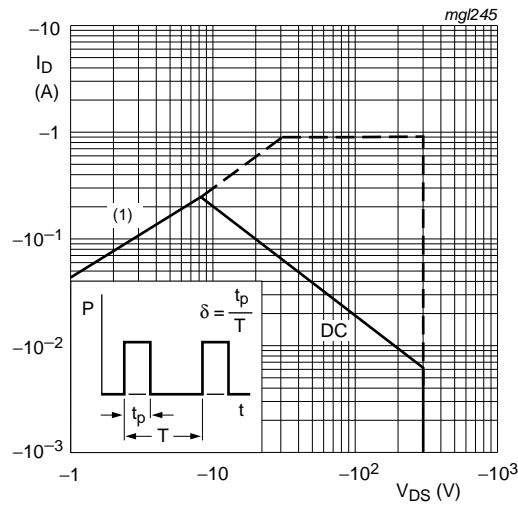


Fig 2. SOAR; N-channel



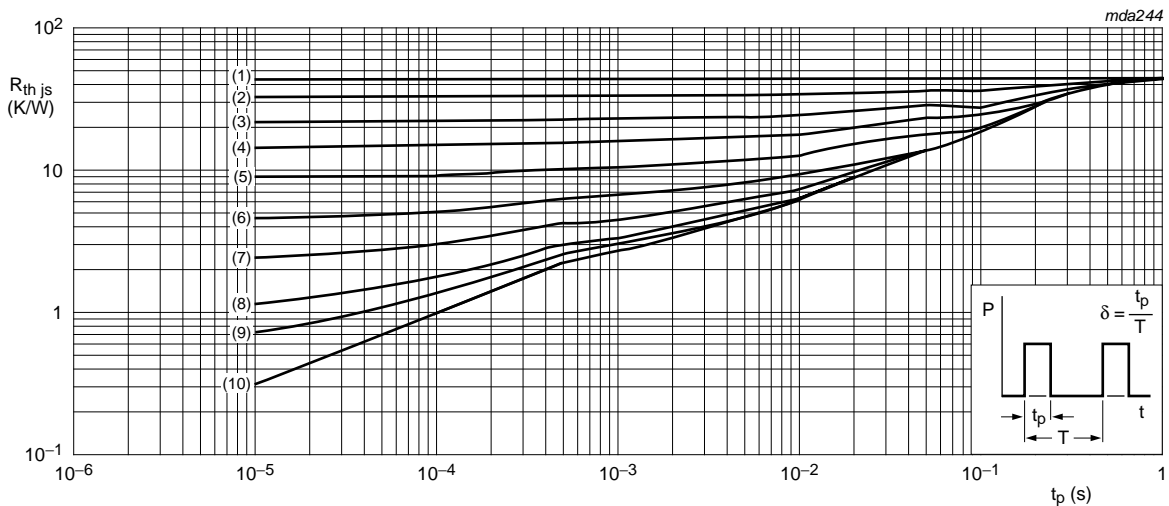
$\delta = 0.01$; $T_{sp} = 80\text{ }^{\circ}\text{C}$.
 (1) R_{DSon} limitation.

Fig 3. SOAR; P-channel

5. Thermal characteristics

Table 5. Thermal characteristics

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
|----------------|--|------------|-----|-----|-----|------|
| $R_{th(j-sp)}$ | thermal resistance from junction to solder point | | - | - | 43 | K/W |



(1) $\delta = 1.00$. (2) $\delta = 0.75$. (3) $\delta = 0.5$. (4) $\delta = 0.33$. (5) $\delta = 0.2$.
 (6) $\delta = 0.1$. (7) $\delta = 0.05$. (8) $\delta = 0.02$. (9) $\delta = 0.01$. (10) $\delta = 0$.

Fig 4. Transient thermal resistance from junction to soldering point as a function of pulse time for N- and P-channel; typical values

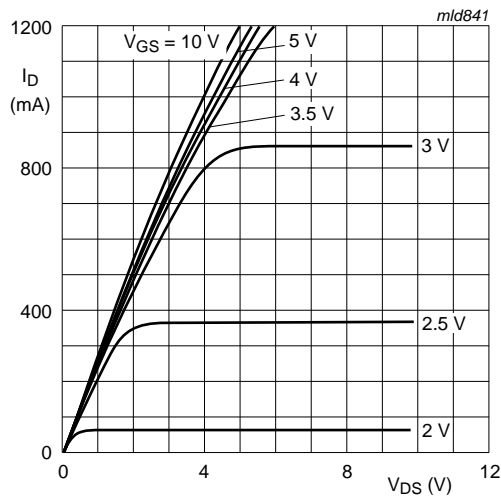
6. Characteristics

Table 6. Characteristics

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
|--------------------------------|----------------------------------|---|------|------|------|----------|
| Static characteristics | | | | | | |
| $V_{(BR)DSS}$ | drain-source breakdown voltage | $I_D = -10 \mu\text{A}$; $V_{GS} = 0 \text{ V}$; $T_j = 25 \text{ }^\circ\text{C}$; P-channel | -300 | - | - | V |
| | | $I_D = 10 \mu\text{A}$; $V_{GS} = 0 \text{ V}$; $T_j = 25 \text{ }^\circ\text{C}$; N-channel | 300 | - | - | V |
| $V_{GS(th)}$ | gate-source threshold voltage | $I_D = 1 \text{ mA}$; $V_{DS} = V_{GS}$; $T_j = 25 \text{ }^\circ\text{C}$; N-channel | 0.8 | - | 2 | V |
| | | $I_D = -1 \text{ mA}$; $V_{DS} = V_{GS}$; $T_j = 25 \text{ }^\circ\text{C}$; P-channel | -0.8 | - | -2 | V |
| I_{DSS} | drain leakage current | $V_{DS} = -240 \text{ V}$; $V_{GS} = 0 \text{ V}$; $T_j = 25 \text{ }^\circ\text{C}$; P-channel | - | - | -100 | nA |
| | | $V_{DS} = 240 \text{ V}$; $V_{GS} = 0 \text{ V}$; $T_j = 25 \text{ }^\circ\text{C}$; N-channel | - | - | 100 | nA |
| I_{GSS} | gate leakage current | $V_{GS} = 20 \text{ V}$; $V_{DS} = 0 \text{ V}$; $T_j = 25 \text{ }^\circ\text{C}$; N-channel | - | - | 100 | nA |
| | | $V_{GS} = -20 \text{ V}$; $V_{DS} = 0 \text{ V}$; $T_j = 25 \text{ }^\circ\text{C}$; N-channel | - | - | 100 | nA |
| | | $V_{GS} = 20 \text{ V}$; $V_{DS} = 0 \text{ V}$; $T_j = 25 \text{ }^\circ\text{C}$; P-channel | - | - | 100 | nA |
| | | $V_{GS} = -20 \text{ V}$; $V_{DS} = 0 \text{ V}$; $T_j = 25 \text{ }^\circ\text{C}$; P-channel | - | - | 100 | nA |
| $R_{DS(on)}$ | drain-source on-state resistance | $V_{GS} = 10 \text{ V}$; $I_D = 170 \text{ mA}$; $T_j = 25 \text{ }^\circ\text{C}$; N-channel | - | - | 6 | Ω |
| | | $V_{GS} = -10 \text{ V}$; $I_D = -115 \text{ mA}$; $T_j = 25 \text{ }^\circ\text{C}$; P-channel | - | - | 17 | Ω |
| Dynamic characteristics | | | | | | |
| $Q_{G(tot)}$ | total gate charge | $I_D = 170 \text{ mA}$; $V_{DS} = 50 \text{ V}$; $V_{GS} = 10 \text{ V}$; $T_j = 25 \text{ }^\circ\text{C}$; N-channel | - | 6240 | - | pC |
| | | $I_D = -115 \text{ mA}$; $V_{DS} = -50 \text{ V}$; $V_{GS} = -10 \text{ V}$; $T_j = 25 \text{ }^\circ\text{C}$; P-channel | - | 2137 | - | pC |
| Q_{GS} | gate-source charge | $I_D = 170 \text{ mA}$; $V_{DS} = 50 \text{ V}$; $V_{GS} = 10 \text{ V}$; $T_j = 25 \text{ }^\circ\text{C}$; N-channel | - | 226 | - | pC |
| | | $I_D = -115 \text{ mA}$; $V_{DS} = -50 \text{ V}$; $V_{GS} = -10 \text{ V}$; $T_j = 25 \text{ }^\circ\text{C}$; P-channel | - | 68 | - | pC |
| Q_{GD} | gate-drain charge | $I_D = 170 \text{ mA}$; $V_{DS} = 50 \text{ V}$; $V_{GS} = 10 \text{ V}$; $T_j = 25 \text{ }^\circ\text{C}$; N-channel | - | 1385 | - | pC |
| | | $I_D = -115 \text{ mA}$; $V_{DS} = -50 \text{ V}$; $V_{GS} = -10 \text{ V}$; $T_j = 25 \text{ }^\circ\text{C}$; P-channel | - | 674 | - | pC |
| C_{iss} | input capacitance | $V_{DS} = 50 \text{ V}$; $V_{GS} = 0 \text{ V}$; $f = 1 \text{ MHz}$; $T_j = 25 \text{ }^\circ\text{C}$; N-channel | - | 102 | - | pF |
| | | $V_{DS} = -50 \text{ V}$; $V_{GS} = 0 \text{ V}$; $f = 1 \text{ MHz}$; $T_j = 25 \text{ }^\circ\text{C}$; P-channel | - | 45 | - | pF |
| C_{oss} | output capacitance | $V_{DS} = 50 \text{ V}$; $V_{GS} = 0 \text{ V}$; $f = 1 \text{ MHz}$; $T_j = 25 \text{ }^\circ\text{C}$; N-channel | - | 15 | - | pF |
| | | $V_{DS} = -50 \text{ V}$; $V_{GS} = 0 \text{ V}$; $f = 1 \text{ MHz}$; $T_j = 25 \text{ }^\circ\text{C}$; P-channel | - | 15 | - | pF |

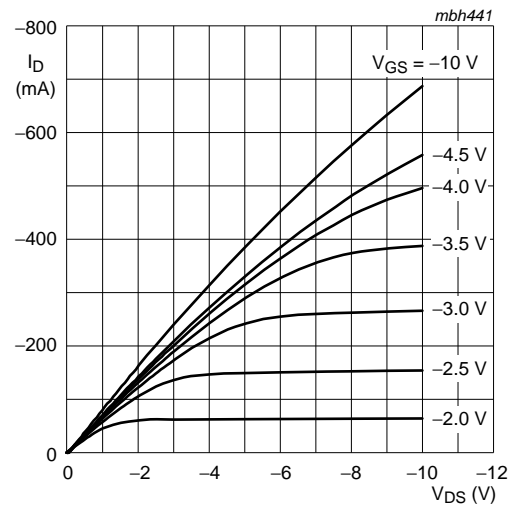
Table 6. Characteristics ...continued

| Symbol | Parameter | Conditions | Min | Typ | Max | Unit |
|-----------|------------------------------|--|-----|-----|-----|------|
| C_{rss} | reverse transfer capacitance | $V_{DS} = 50\text{ V}; V_{GS} = 0\text{ V}; f = 1\text{ MHz}; T_j = 25\text{ }^\circ\text{C}; \text{N-channel}$ | - | 7.3 | - | pF |
| | | $V_{DS} = -50\text{ V}; V_{GS} = 0\text{ V}; f = 1\text{ MHz}; T_j = 25\text{ }^\circ\text{C}; \text{P-channel}$ | - | 3 | - | pF |
| t_{on} | turn-on time | $V_{DS} = 50\text{ V}; V_{GS} = 10\text{ V}; I_D = 170\text{ mA}; T_j = 25\text{ }^\circ\text{C}; \text{N-channel}$ | - | 7 | 12 | ns |
| | | $V_{DS} = -50\text{ V}; V_{GS} = -10\text{ V}; I_D = -115\text{ mA}; T_j = 25\text{ }^\circ\text{C}; \text{P-channel}$ | - | 4 | 10 | ns |
| t_{off} | turn-off time | $V_{DS} = 50\text{ V}; V_{GS} = 10\text{ V}; T_j = 25\text{ }^\circ\text{C}; I_D = 170\text{ mA}; \text{N-channel}$ | - | 53 | 65 | ns |
| | | $V_{DS} = -50\text{ V}; V_{GS} = -10\text{ V}; T_j = 25\text{ }^\circ\text{C}; I_D = -115\text{ mA}; \text{P-channel}$ | - | 25 | 35 | ns |



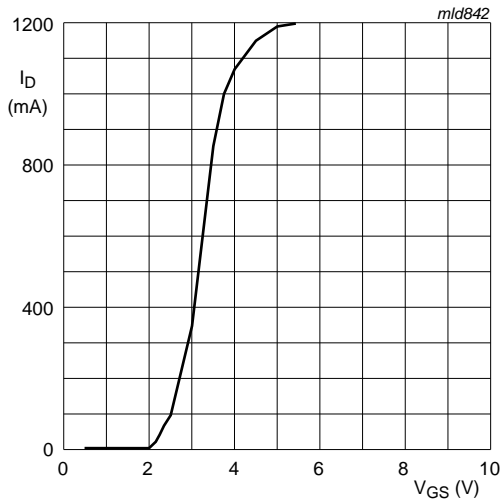
$T_{amb} = 25\text{ }^\circ\text{C}; t_p = 80\text{ }\mu\text{s}; \delta = 0.$

Fig 5. Output characteristics: drain current as a function of drain-source voltage; N-channel; typical values



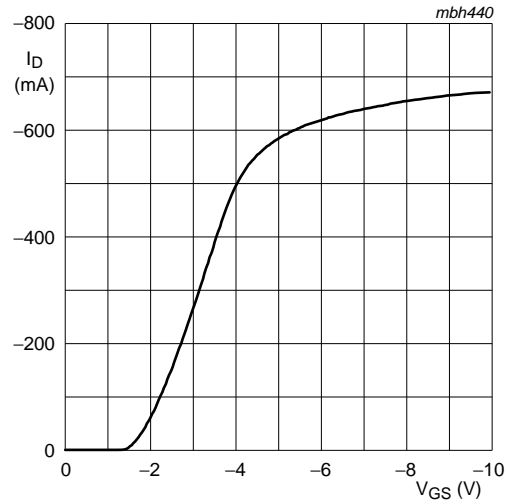
$T_{amb} = 25\text{ }^\circ\text{C}; t_p = 80\text{ }\mu\text{s}; \delta = 0.$

Fig 6. Output characteristics: drain current as a function of drain-source voltage; P-channel; typical values



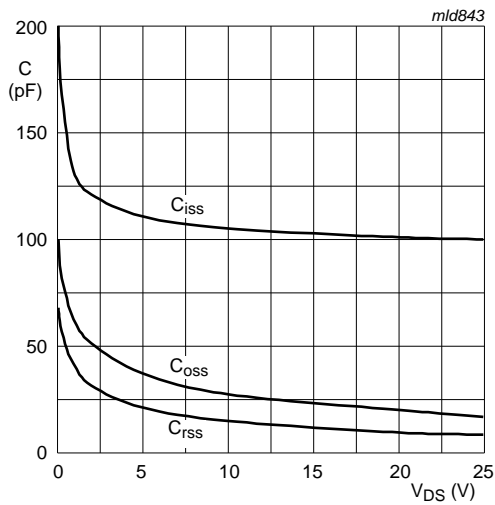
$V_{DS} = 10\text{ V}; T_{amb} = 25\text{ }^\circ\text{C}; t_p = 80\text{ }\mu\text{s}; \delta = 0.$

Fig 7. Transfer characteristics: drain current as a function of gate-source voltage; N-channel; typical values



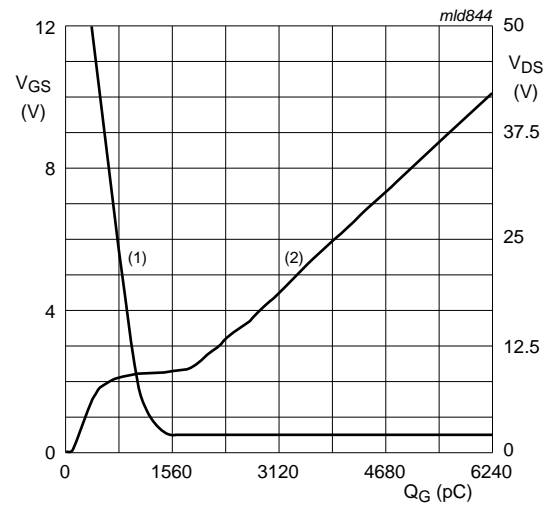
$V_{DS} = -10\text{ V}; T_{amb} = 25\text{ }^\circ\text{C}; t_p = 80\text{ }\mu\text{s}; \delta = 0.$

Fig 8. Transfer characteristics: drain current as a function of gate-source voltage; P-channel; typical values



$T_{amb} = 25\text{ }^\circ\text{C}; f = 1\text{ MHz}$

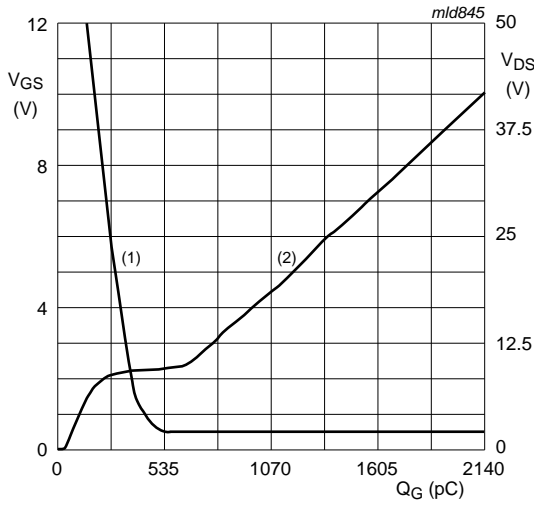
Fig 9. Input, output and reverse transfer capacitances as a function of drain-source voltage; N-channel; typical values



$V_{DS} = 50\text{ V}; I_D = 170\text{ mA}; T_{amb} = 25\text{ }^\circ\text{C}.$

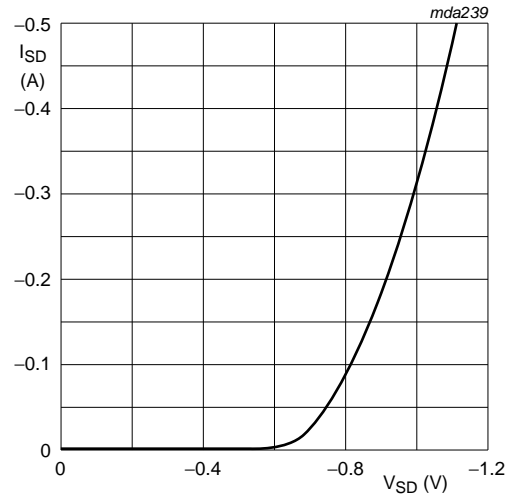
(1) V_{DS}
(2) V_{GS}

Fig 10. Gate-source voltage and drain-source voltage as a function of gate charge; N-channel typical values



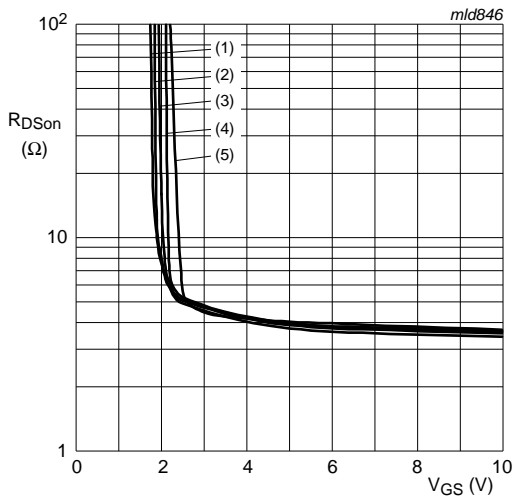
$V_{DS} = -50\text{ V}$; $I_D = -115\text{ mA}$; $T_{amb} = 25\text{ }^\circ\text{C}$.
 (1) V_{DS}
 (2) V_{GS}

Fig 11. Gate-source voltage and drain-source voltage as a function of gate charge; P-channel typical values



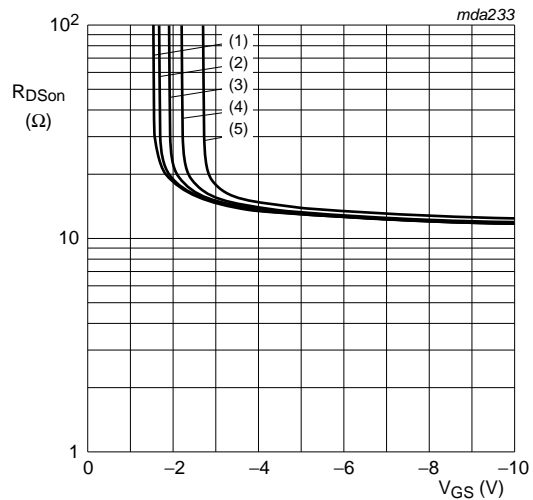
$V_{GD} = 0\text{ V}$

Fig 12. Source current as a function of source-drain voltage; P-channel typical values



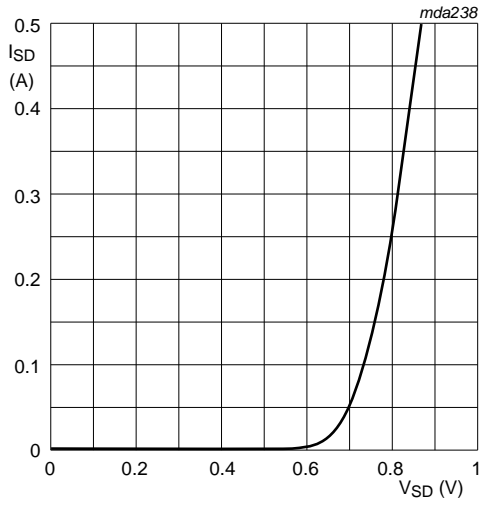
$V_{DS} \geq I_D \times R_{DSon}$; $T_{amb} = 25\text{ }^\circ\text{C}$; $t_p = 300\text{ }\mu\text{s}$; $\delta = 0$.
 (1) $I_D = 10\text{ mA}$.
 (2) $I_D = 20\text{ mA}$.
 (3) $I_D = 50\text{ mA}$.
 (4) $I_D = 100\text{ mA}$.
 (5) $I_D = 200\text{ mA}$.

Fig 13. Drain-source on-state resistance as a function of gate-source voltage; N-channel typical values



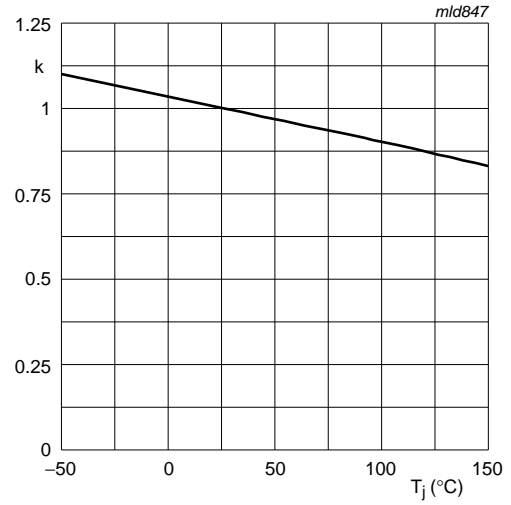
$V_{DS} \geq I_D \times R_{DSon}$; $T_{amb} = 25\text{ }^\circ\text{C}$; $t_p = 300\text{ }\mu\text{s}$; $\delta = 0$.
 (1) $I_D = -10\text{ mA}$.
 (2) $I_D = -20\text{ mA}$.
 (3) $I_D = -50\text{ mA}$.
 (4) $I_D = -100\text{ mA}$.
 (5) $I_D = -200\text{ mA}$.

Fig 14. Drain-source on-state resistance as a function of gate-source voltage; P-channel typical values



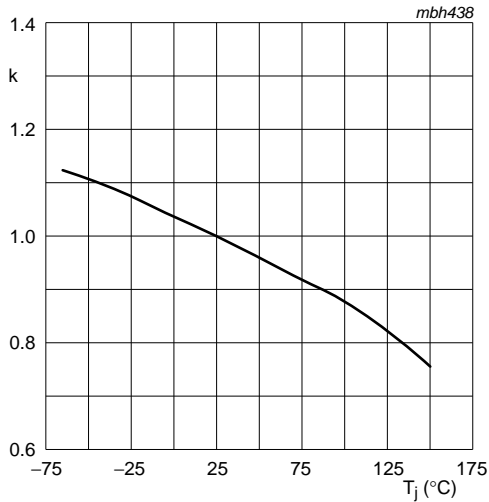
$V_{GD} = 0V$

Fig 15. Source-drain current as a function of source-drain diode voltage; N-channel; typical values



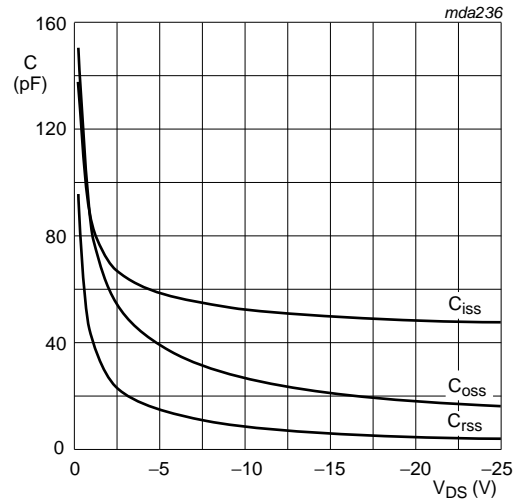
$V_{DS} = V_{GS}; I_D = 1 \text{ mA.}$

Fig 16. Temperature coefficient of gate-source threshold voltage as a function temperature; N-channel; typical values



$V_{DS} = V_{GS}; I_D = -1 \text{ mA.}$

Fig 17. Temperature coefficient of gate-source threshold voltage as a function temperature; P-channel; typical values



$T_{amb} = 25^\circ C; f = 1MHz$

Fig 18. Input, output and reverse transfer capacitances as a function of drain-source voltage; typical values

7. Package outline

SO8: plastic small outline package; 8 leads; body width 3.9 mm

SOT96-1

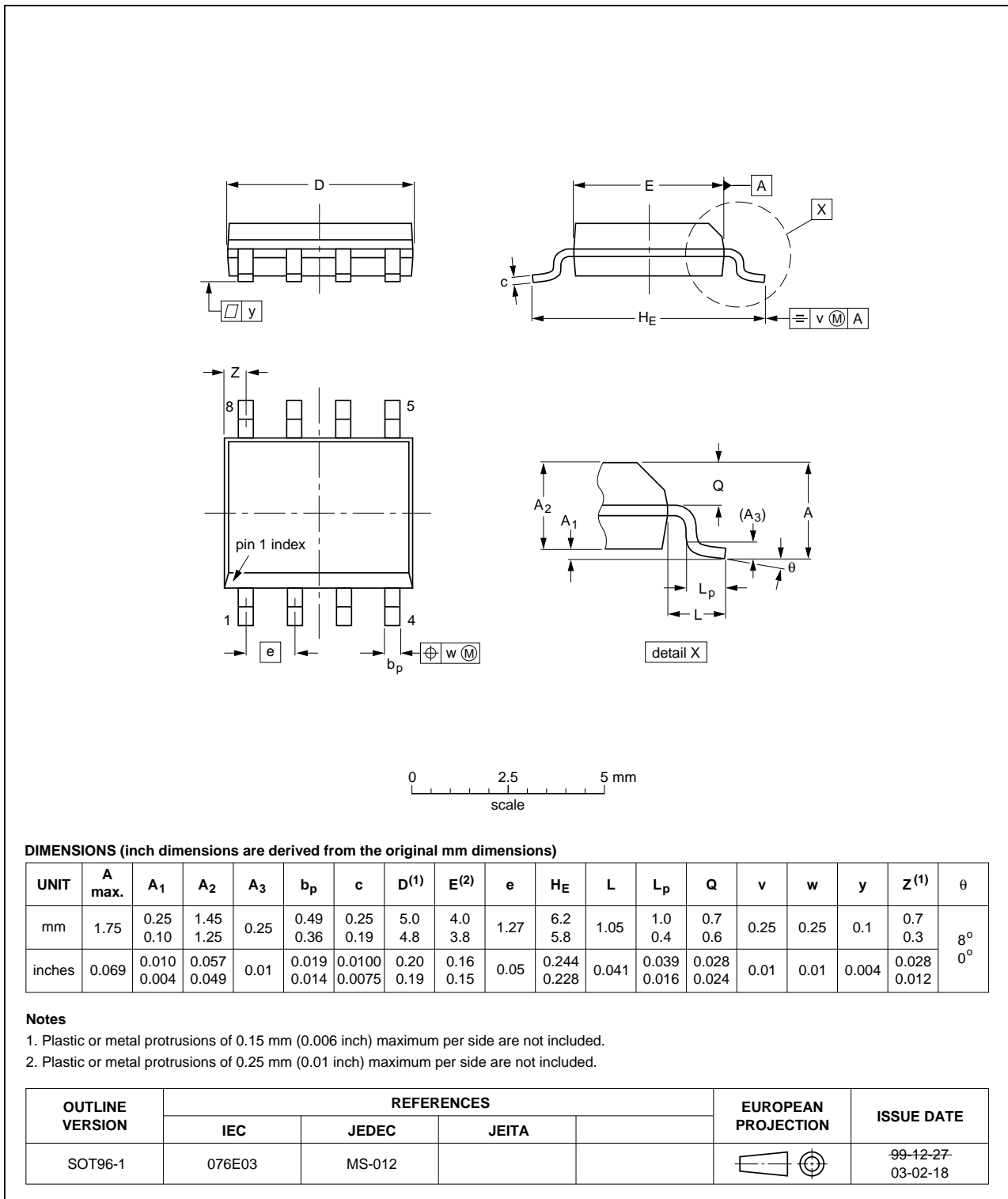


Fig 19. Package outline SOT96-1 (SO8)

8. Revision history

Table 7. Revision history

| Document ID | Release date | Data sheet status | Change notice | Supersedes |
|----------------|-------------------------------|--------------------|---------------|-------------|
| PHC2300 v.5 | 20110224 | Product data sheet | - | PHC2300 v.4 |
| Modifications: | • Various changes to content. | | | |
| PHC2300 v.4 | 20101216 | Product data sheet | - | PHC2300 v.3 |

9. Legal information

9.1 Data sheet status

| Document status ^[1] ^[2] | Product status ^[3] | Definition |
|---|-------------------------------|---|
| Objective [short] data sheet | Development | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet | Qualification | This document contains data from the preliminary specification. |
| Product [short] data sheet | Production | This document contains the product specification. |

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL <http://www.nexperia.com>.

9.2 Definitions

Draft — The document is a draft version only. The content is still under internal review and subject to formal approval, which may result in modifications or additions. Nexperia does not give any representations or warranties as to the accuracy or completeness of information included herein and shall have no liability for the consequences of use of such information.

Short data sheet — A short data sheet is an extract from a full data sheet with the same product type number(s) and title. A short data sheet is intended for quick reference only and should not be relied upon to contain detailed and full information. For detailed and full information see the relevant full data sheet, which is available on request via the local Nexperia sales office. In case of any inconsistency or conflict with the short data sheet, the full data sheet shall prevail.

Product specification — The information and data provided in a Product data sheet shall define the specification of the product as agreed between Nexperia and its customer, unless Nexperia and customer have explicitly agreed otherwise in writing. In no event however, shall an agreement be valid in which the Nexperia product is deemed to offer functions and qualities beyond those described in the Product data sheet.

9.3 Disclaimers

Limited warranty and liability — Information in this document is believed to be accurate and reliable. However, Nexperia does not give any representations or warranties, expressed or implied, as to the accuracy or completeness of such information and shall have no liability for the consequences of use of such information.

In no event shall Nexperia be liable for any indirect, incidental, punitive, special or consequential damages (including - without limitation - lost profits, lost savings, business interruption, costs related to the removal or replacement of any products or rework charges) whether or not such damages are based on tort (including negligence), warranty, breach of contract or any other legal theory.

Notwithstanding any damages that customer might incur for any reason whatsoever, Nexperia's aggregate and cumulative liability towards customer for the products described herein shall be limited in accordance with the *Terms and conditions of commercial sale* of Nexperia.

Right to make changes — Nexperia reserves the right to make changes to information published in this document, including without limitation specifications and product descriptions, at any time and without notice. This document supersedes and replaces all information supplied prior to the publication hereof.

Suitability for use — Nexperia products are not designed, authorized or warranted to be suitable for use in life support, life-critical or safety-critical systems or equipment, nor in applications where failure or malfunction of a Nexperia product can reasonably be expected to result in personal injury, death or severe property or environmental damage. Nexperia accepts no liability for inclusion and/or use of Nexperia products in such equipment or applications and therefore such inclusion and/or use is at the customer's own risk.

Quick reference data — The Quick reference data is an extract of the product data given in the Limiting values and Characteristics sections of this document, and as such is not complete, exhaustive or legally binding.

Applications — Applications that are described herein for any of these products are for illustrative purposes only. Nexperia makes no representation or warranty that such applications will be suitable for the specified use without further testing or modification.

Customers are responsible for the design and operation of their applications and products using Nexperia products, and Nexperia accepts no liability for any assistance with applications or customer product design. It is customer's sole responsibility to determine whether the Nexperia product is suitable and fit for the customer's applications and products planned, as well as for the planned application and use of customer's third party customer(s). Customers should provide appropriate design and operating safeguards to minimize the risks associated with their applications and products.

Nexperia does not accept any liability related to any default, damage, costs or problem which is based on any weakness or default in the customer's applications or products, or the application or use by customer's third party customer(s). Customer is responsible for doing all necessary testing for the customer's applications and products using Nexperia products in order to avoid a default of the applications and the products or of the application or use by customer's third party customer(s). Nexperia does not accept any liability in this respect.

Limiting values — Stress above one or more limiting values (as defined in the Absolute Maximum Ratings System of IEC 60134) will cause permanent damage to the device. Limiting values are stress ratings only and (proper) operation of the device at these or any other conditions above those given in the Recommended operating conditions section (if present) or the Characteristics sections of this document is not warranted. Constant or repeated exposure to limiting values will permanently and irreversibly affect the quality and reliability of the device.

Terms and conditions of commercial sale — Nexperia products are sold subject to the general terms and conditions of commercial sale, as published at <http://www.nexperia.com/profile/terms>, unless otherwise agreed in a valid written individual agreement. In case an individual agreement is concluded only the terms and conditions of the respective

agreement shall apply. Nexperia hereby expressly objects to applying the customer's general terms and conditions with regard to the purchase of Nexperia products by customer.

No offer to sell or license — Nothing in this document may be interpreted or construed as an offer to sell products that is open for acceptance or the grant, conveyance or implication of any license under any copyrights, patents or other industrial or intellectual property rights.

Export control — This document as well as the item(s) described herein may be subject to export control regulations. Export might require a prior authorization from national authorities.

Non-automotive qualified products — Unless this data sheet expressly states that this specific Nexperia product is automotive qualified, the product is not suitable for automotive use. It is neither qualified nor tested in accordance with automotive testing or application requirements. Nexperia accepts no liability for inclusion and/or use of non-automotive qualified products in automotive equipment or applications.

In the event that customer uses the product for design-in and use in automotive applications to automotive specifications and standards, customer (a) shall use the product without Nexperia's warranty of the

product for such automotive applications, use and specifications, and (b) whenever customer uses the product for automotive applications beyond Nexperia's specifications such use shall be solely at customer's own risk, and (c) customer fully indemnifies Nexperia for any liability, damages or failed product claims resulting from customer design and use of the product for automotive applications beyond Nexperia's standard warranty and Nexperia's product specifications.

9.4 Trademarks

Notice: All referenced brands, product names, service names and trademarks are the property of their respective owners.

10. Contact information

For more information, please visit: <http://www.nexperia.com>

For sales office addresses, please send an email to: salesaddresses@nexperia.com

11. Contents

| | | |
|-----------|--|-----------|
| 1 | Product profile | 1 |
| 1.1 | General description | 1 |
| 1.2 | Features and benefits | 1 |
| 1.3 | Applications | 1 |
| 1.4 | Quick reference data | 1 |
| 2 | Pinning information | 2 |
| 3 | Ordering information | 2 |
| 4 | Limiting values | 3 |
| 5 | Thermal characteristics | 4 |
| 6 | Characteristics | 5 |
| 7 | Package outline | 10 |
| 8 | Revision history | 11 |
| 9 | Legal information | 12 |
| 9.1 | Data sheet status | 12 |
| 9.2 | Definitions | 12 |
| 9.3 | Disclaimers | 12 |
| 9.4 | Trademarks | 13 |
| 10 | Contact information | 13 |